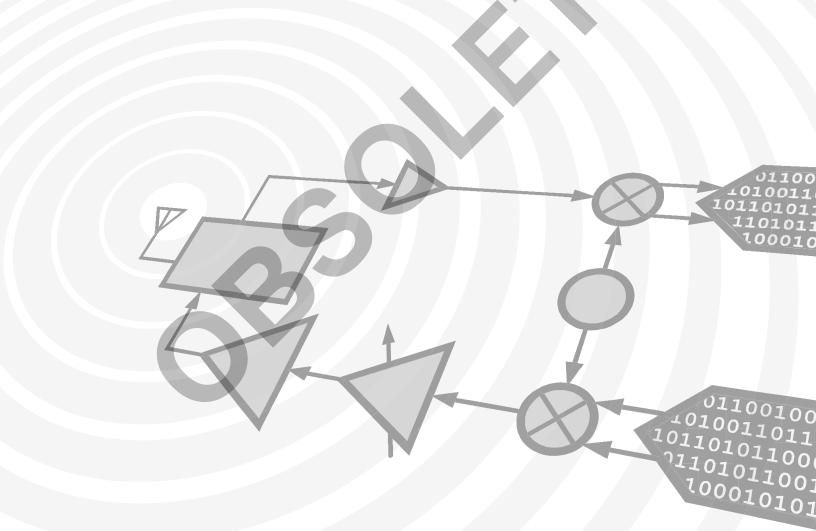




Analog Devices Welcomes Hittite Microwave Corporation

NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED







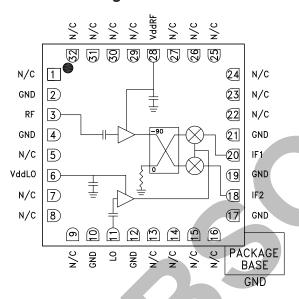


Typical Applications

The HMC567LC5 is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- EW & ELINT

Functional Diagram



Features

Conversion Gain: 10 dB Image Rejection: 35 dB LO to RF Isolation: 54 dB Noise Figure: 2.5 dB

Input IP3: +1.5 dBm

32 Lead 5x5mm SMT Package: 25mm²

General Description

The HMC567LC5 is a compact GaAs MCM I/Q downconverter in a leadless RoHS compliant SMT package. This device provides a small signal conversion gain of 10 dB with a noise figure of 2.5 dB and 35 dB of image rejection across the frequency band. The HMC567LC5 utilizes an LNA followed by an image reject mixer which is driven by an LO buffer amplifier. The image reject mixer eliminates the need for a filter following the LNA, and removes thermal noise at the image frequency. I and Q mixer outputs are provided and an external 90° hybrid is needed to select the required sideband. The HMC567LC5 is a much smaller alternative to hybrid style image reject mixer downconverter assemblies, and it eliminates the need for wire bonding by allowing the use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25$ °C, IF = 100 MHz, LO = 0 dBm, VddLO = 5.0 Vdc, VddRF = 3.0 Vdc*

	Min. Typ.	Max.	Units	
Frequency Range, RF		7 - 9		
ncy Range, LO 3.5 - 12.5			GHz	
DC - 3.5 G			GHz	
	7 10		dB	
	2.5		dB	
Image Rejection			dB	
1 dB Compression (Input)			dBm	
	43 54		dB	
	20 32		dB	
	+1.5		dBm	
	±0.75	5	dB	
	±3		Deg	
Total Supply Current		195	mA	
		100	160 195	

^{*}Data taken as IRM with external IF Hybrid





Data Taken As IRM With External IF Hybrid

Conversion Gain vs. Temperature

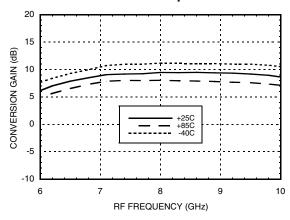
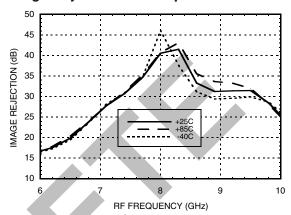
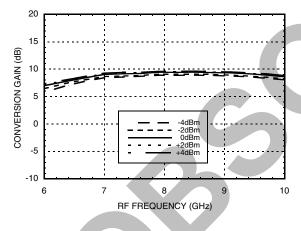


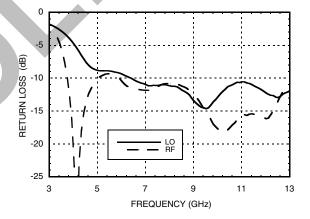
Image Rejection vs. Temperature



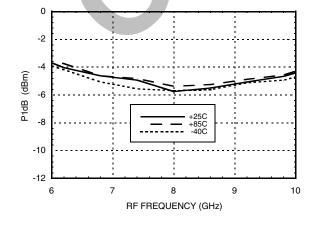
Conversion Gain vs. LO Drive



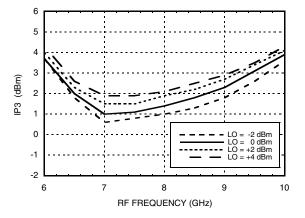
Return Loss



Input P1dB vs. Temperature



Input IP3 vs. LO Drive

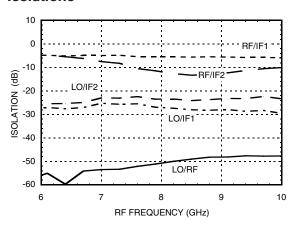




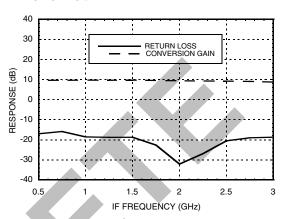


Quadrature Channel Data Taken Without IF Hybrid

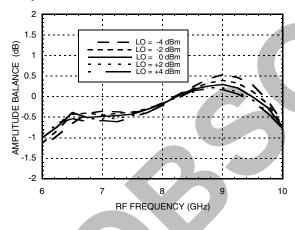
Isolations



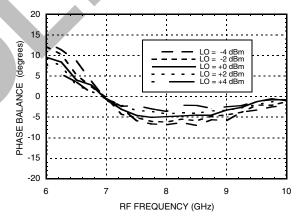
IF Bandwidth*



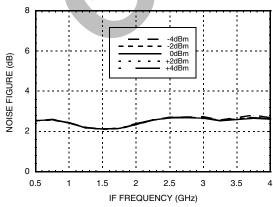
Amplitude Balance vs. LO Drive



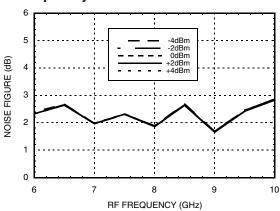
Phase Balance vs. LO Drive



Noise Figure vs. LO Drive, LO Frequency = 7.0 GHz



Noise Figure vs. LO Drive, IF Frequency = 100 MHz



^{*} Conversion gain data taken with external IF hybrid, LO frequency fixed at 7.0 GHz and RF varied





MxN Spurious Outputs

	nLO				
mRF	0	1	2	3	4
0	xx	15	48	42	60
1	13	0	29	48	66
2	63	53	59	59	84
3	79	93	83	52	76
4	104	103	104	107	97

RF = 7.6 GHz @ -20 dBm LO = 7.5 GHz @ +4 dBm Data taken without IF hybrid

All values in dBc below IF power level.

Absolute Maximum Ratings

RF	+5 dBm
LO Drive	+20 dBm
VddRF / VddLO	4.0V / 5.5V
Channel Temperature	150°C
Continuous Pdiss (T=85°C) (derate 9.56 mW/°C above 85°C)	508 mW
Thermal Resistance (R _{TH}) (channel to package bottom)	77 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

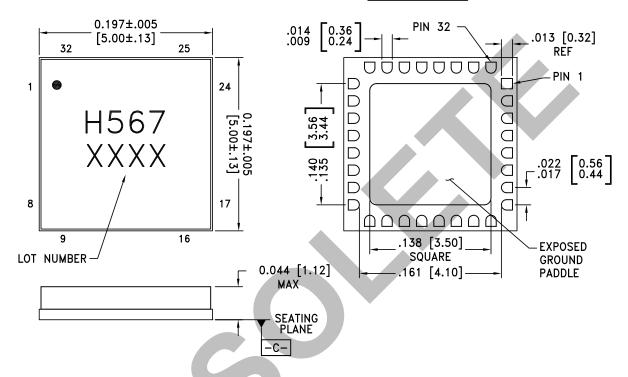






Outline Drawing

BOTTOM VIEW



NOTES:

- 1. PACKAGE BODY MATERIAL: ALUMINA
- 2. LEAD AND GROUND PADDLE PLATING: 30 80 MICROINCHES
- GOLD OVER 50 MICROINCHES MINIMUM NICKLE
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND

Package Information

Part	Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
НМС	C567LC5	Alumina, White	Gold over Nickel	MSL3 ^[1]	H567 XXXX

^[1] Max peak reflow temperature of 260 °C

^{[2] 4-}Digit lot number XXXX

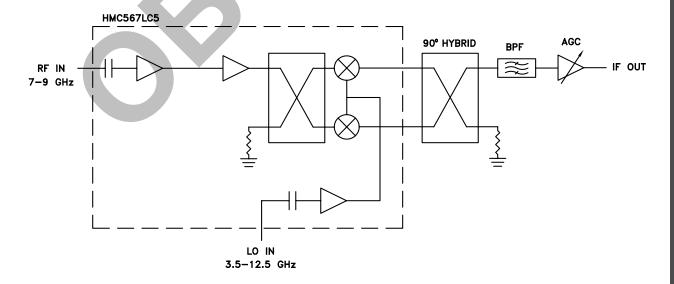




Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 5, 7 - 9, 13 - 16, 22 - 27, 29 - 32	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	
2, 4, 10, 12, 17, 19, 21	GND	These pins and ground paddle must be connected to RF/DC ground.	O GND
3	RF	This pin is AC coupled and matched to 50 Ohms.	RF O—
6	VddLO	Power supply for LO amplifier. 100 mA typical, 120 mA maximum.	VddLO 🌣
28	VddRF	Power supply for RF LNA. 60 mA typical, 75 mA maximum.	VddRF ○
18	IF2	This pin is DC coupled for applications not requiring operation to DC. This port should be DC blocked externally using a series capacitor whose value has	IF1,IF2
20	IF1	been chosen to pass the necessary frequency range. For operation to DC, this pin must not sink / source more than 3 mA of current or part non-function and possible failure will result.	¥ ‡
11	LO	This pin is AC coupled and matched to 50 Ohms.	L0 0— —

Typical Application

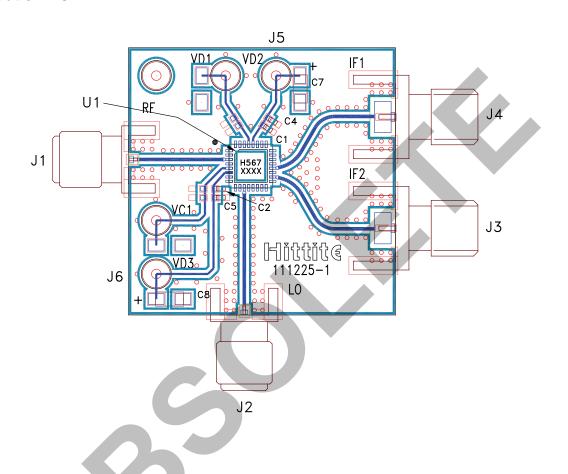


Note: LSB and USB is determined by GND on Hybrid





Evaluation PCB



List of Materials for Evaluation PCB 111239 [1]

Item	Description	
C1, C2	Capacitor 0402, Pkg. 100pF	
C4, C5	Capacitor 0402, Pkg. 1000pF	
C7, C8	Capacitor, Case A, 2.2uF *(Polarity)	
J1, J2	PCB Mount SMA RF Connector, SRI	
J3, J4	PCB Mount SMA Connector, Johnson	
J5	DC Pin, VD2 = VddRF	
J6	DC Pin, VD3 = VddLO	
VC1, VD1	N/C	
U1	HMC567LC5	
PCB [2]	111225 Evaluation Board	

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Rogers 4350





